**TEXAS INSTRUMENTS**

**TS3A5017**

SCDS188G − JANUARY 2005 − REVISED JANUARY 2019

## TS3A5017 Dual SP4T Analog Switch / Multiplexer / Demultiplexer

### 1 Features

- Isolation in the Powered-Down Mode, $V_+ = 0$
- Low ON-State Resistance
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 2.3-V to 3.6-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 1500-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)

### 2 Applications

- Sample-and-Hold Circuits
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits

### 3 Description

The TS3A5017 device is a dual single-pole quadruple-throw (4:1) analog switch that is designed to operate from 2.3 V to 3.6 V. This device can handle both digital and analog signals, and signals up to $V_+$ can be transmitted in either direction.

#### Device Information[1]

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|---|---|---|
| TS3A5017 | SOIC (16) | 9.90 mm × 3.90 mm |
| | SSOP (16) | 4.90 mm × 3.90 mm |
| | TSSOP (16) | 5.00 mm × 4.40 mm |
| | TVSOP (16) | 4.40 mm × 3.60 mm |
| | UQFN (16) | 2.50 mm × 1.80 mm |
| | VQFN (16) | 4.00 mm × 3.50 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.
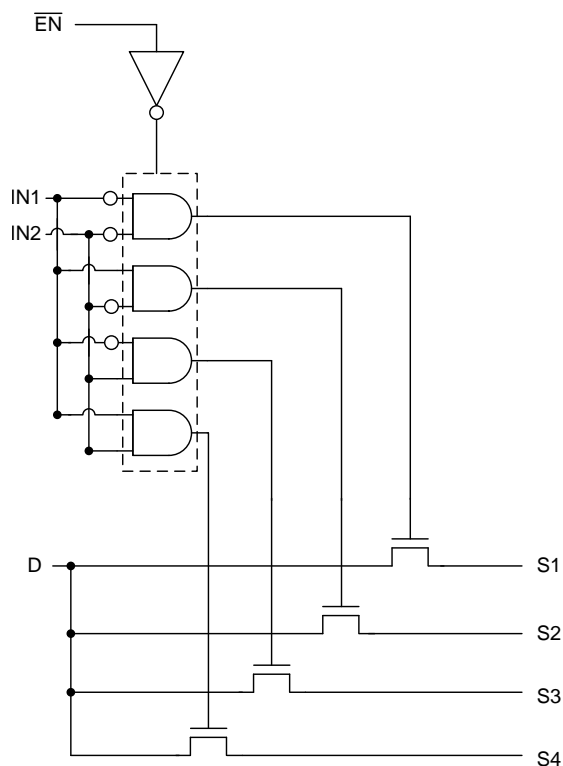
**Block Diagram**

## Table of Contents

## 4 Revision History

**Changes from Revision F (October 2018) to Revision G**      **Page**

• Changed *Feature* From: 2000-V Human-Body Model To: 1500-V Human-Body Model ....................................................... 1
• Changed the HBM value From: ±2000 V To: ±1500 V in the *ESD Ratings*............................................................... 4

**Changes from Revision E (April 2015) to Revision F**      **Page**

• Changed the $X_{TALK}$ MAX value From:–49 dB To – 69 dB in the *Electrical Characteristics for 3.3-V Supply*........................ 6

**Changes from Revision D (December 2008) to Revision E**      **Page**

• Added *Applications*, *Device Information* table, *Pin Functions* table, *ESD Ratings* table, *Thermal Information* table, *Typical Characteristics*, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section. ............................................................... 1
• Deleted *Ordering Information* table. ............................................................... 1

# 5 Pin Configuration and Functions

**D, DBQ, DGV, and PW Package**
**16-Pin SOIC, SSOP, TVSOP and TSSOP**
**(Top View)**
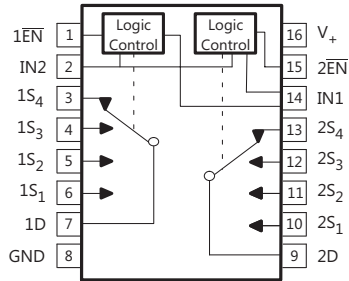


**RGY Package**
**16-Pin VQFN**
**(Top View)**
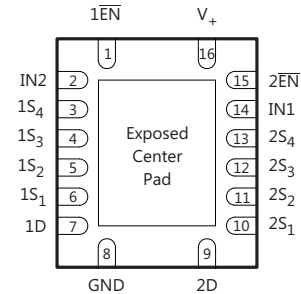


If exposed center pad is used, it must be connected as a secondary ground or left electrically open.

**RSV Package**
**16-Pin UQFN**
**(Top View)**
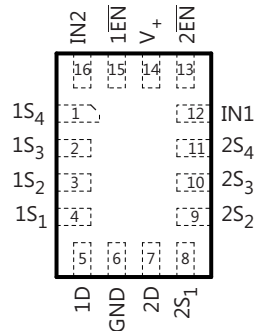


## Pin Functions

| PIN | | | TYPE | DESCRIPTION |
|---|---|---|---|---|
| NAME | SOIC, SSOP, TVSOP, TSSOP, VQFN NO. | UQFN NO. | | |
| 1D | 7 | 5 | I/O | Common path for switch 1 |
| 1$\overline{\text{EN}}$ | 1 | 15 | I | Active-low enable for switch 1 |
| 1S1 | 6 | 4 | I/O | Switch 1 channel 1 |
| 1S2 | 5 | 3 | I/O | Switch 1 channel 2 |
| 1S3 | 4 | 2 | I/O | Switch 1 channel 3 |
| 1S4 | 3 | 1 | I/O | Switch 1 channel 4 |
| 2D | 9 | 7 | I/O | Common path for switch 2 |
| 2$\overline{\text{EN}}$ | 15 | 13 | I | Active-low enable for switch 2 |
| 2S1 | 10 | 8 | I/O | Switch 2 channel 1 |
| 2S2 | 11 | 9 | I/O | Switch 2 channel 2 |
| 2S3 | 12 | 10 | I/O | Switch 2 channel 3 |
| 2S4 | 13 | 11 | I/O | Switch 2 channel 4 |
| GND | 8 | 6 | – | Ground |
| IN1 | 14 | 12 | I | Switch 1 input select |
| IN2 | 2 | 16 | I | Switch 2 input select |
| V+ | 16 | 14 | – | Supply voltage |

# 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1][2]

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_+$ | Supply voltage[3] | | −0.5 | 4.6 | V |
| $V_S$, $V_D$ | Analog voltage[3][4] | | −0.5 | 4.6 | V |
| $I_{SK}$, $I_{DK}$ | Analog port clamp current | $V_S$, $V_D$ < 0 | −50 | | mA |
| $I_S$, $I_D$ | ON-state switch current | $V_S$, $V_D$ = 0 to 7 V | −128 | 128 | mA |
| $V_I$ | Digital input voltage | | −0.5 | 4.6 | V |
| $I_{IK}$ | Digital input clamp current[3][4] | $V_I$ < 0 | −50 | | mA |
| $I_+$ | Continuous current through $V_+$ | | | 100 | mA |
| $I_{GND}$ | Continuous current through GND | | −100 | | mA |
| $T_{stg}$ | Storage temperature | | −65 | 150 | °C |

(1)   Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
(3)   All voltages are with respect to ground, unless otherwise specified.
(4)   The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

## 6.2 ESD Ratings

| | | | VALUE | UNIT |
|---|---|---|---|---|
| $V_{(ESD)}$ | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1] | ±1500 | V |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101[2] | ±1000 | |

(1)   JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| $V_{I/O}$ | Switch input/output voltage range | 0 | 3.6 | V |
| V+ | Supply voltage range | 2.3 | 3.6 | V |
| $V_I$ | Control input voltage range | 0 | 3.6 | V |
| $T_A$ | Operating Temperature Range | −40 | 85 | °C |

## 6.4 Thermal Information

| | | TS3A5018 | | | | | | |
|---|---|---|---|---|---|---|---|---|
| THERMAL METRIC[1] | | D (SOIC) | DBQ (SSOP) | DGV (TVSOP) | PW (TSSOP) | RGY (VQFN) | RSV (UQFN) | UNIT |
| | | 16 PINS | 16 PINS | 16 PINS | 16 PINS | 16 PINS | 16 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 73 | 82 | 120 | 108 | 91.6 | 184 | °C/W |

(1)   For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

Product Folder Links: *TS3A5017*

## 6.5 Electrical Characteristics for 3.3-V Supply

$V_+$ = 2.7 V to 3.6 V, $T_A$ = –40°C to 85°C (unless otherwise noted) [1]

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| **Analog Switch** | | | | | | | | | |
| $V_D$, $V_S$ | Analog signal range | | | | | 0 | | $V_+$ | V |
| $r_{on}$ | ON-state resistance | $0 \leq V_S \leq V_+$, $I_D$ = –32 mA, | Switch ON, see Figure 12 | 25°C | 3 V | | 11 | 12 | Ω |
| | | | | Full | | | | 14 | |
| $\Delta r_{on}$ | ON-state resistance match between channels | $V_S$ = 2.1 V, $I_D$ = –32 mA, | Switch ON, see Figure 12 | 25°C | 3 V | | 1 | 2 | Ω |
| | | | | Full | | | | 3 | |
| $r_{on(flat)}$ | ON-state resistance flatness | $0 \leq V_S \leq V_+$, $I_D$ = –32 mA, | Switch ON, see Figure 12 | 25°C | 3 V | | 7 | 9 | Ω |
| | | | | Full | | | | 10 | |
| $I_{S(OFF)}$ | S OFF leakage current | $V_S$ = 1 V, $V_D$ = 3 V, or $V_S$ = 3 V, $V_D$ = 1 V, | Switch OFF, see Figure 13 | 25°C | 3.6 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{SPWR(OFF)}$ | | $V_S$ = 0 to 3.6 V, $V_D$ = 3.6 V to 0, | | 25°C | 0 V | –1 | 0.5 | 1 | |
| | | | | Full | | –5 | | 5 | |
| $I_{D(OFF)}$ | D OFF leakage current | $V_S$ = 1 V, $V_D$ = 3 V, or $V_S$ = 3 V, $V_D$ = 1 V, | Switch OFF, see Figure 13 | 25°C | 3.6 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{DPWR(OFF)}$ | | $V_D$ = 0 to 3.6 V, $V_S$ = 3.6 V to 0, | | 25°C | 0 V | –1 | 0.5 | 1 | |
| | | | | Full | | –5 | | 5 | |
| $I_{S(ON)}$ | S ON leakage current | $V_S$ = 1 V, $V_D$ = Open, or $V_S$ = 3 V, $V_D$ = Open, | Switch ON, see Figure 14 | 25°C | 3.6 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{D(ON)}$ | D ON leakage current | $V_D$ = 1 V, $V_S$ = Open, or $V_D$ = 3 V, $V_S$ = Open, | Switch ON, see Figure 14 | 25°C | 3.6 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| **Digital Control Inputs (IN1, IN2, $\overline{EN}$)** [2] | | | | | | | | | |
| $V_{IH}$ | Input logic high | | | Full | | 2 | | $V_+$ | V |
| $V_{IL}$ | Input logic low | | | Full | | 0 | | 0.8 | V |
| $I_{IH}$, $I_{IL}$ | Input leakage current | $V_I$ = $V_+$ or 0 | | 25°C | 3.6 V | –1 | 0.05 | 1 | μA |
| | | | | Full | | –1 | | 1 | |
| $Q_C$ | Charge injection | $V_{GEN}$ = 0, $R_{GEN}$ = 0, $C_L$ = 0.1 nF, | See Figure 21 | 25°C | 3.3 V | | 5 | | pC |
| $C_{S(OFF)}$ | S OFF capacitance | $V_S$ = $V_+$ or GND, Switch OFF, | See Figure 15 | 25°C | 3.3 V | | 4.5 | | pF |
| $C_{D(OFF)}$ | D OFF capacitance | $V_D$ = $V_+$ or GND, Switch OFF, | See Figure 15 | 25°C | 3.3 V | | 19 | | pF |
| $C_{S(ON)}$ | S ON capacitance | $V_S$ = $V_+$ or GND, Switch ON, | See Figure 15 | 25°C | 3.3 V | | 25 | | pF |
| $C_{D(ON)}$ | D ON capacitance | $V_D$ = $V_+$ or GND, Switch ON, | See Figure 15 | 25°C | 3.3 V | | 25 | | pF |
| $C_I$ | Digital input capacitance | $V_I$ = $V_+$ or GND, | See Figure 15 | 25°C | 3.3 V | | 2 | | pF |
| BW | Bandwidth | $R_L$ = 50 Ω, Switch ON, | See Figure 17 | 25°C | 3.3 V | | 165 | | MHz |
| $O_{ISO}$ | OFF isolation | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 18 | 25°C | 3.3 V | | –69 | | dB |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $V_+$ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## Electrical Characteristics for 3.3-V Supply (continued)

$V_+$ = 2.7 V to 3.6 V, $T_A$ = –40°C to 85°C (unless otherwise noted)[1]

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| $X_{TALK}$ | Crosstalk | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 19 | 25°C | 3.3 V | | –-69 | | dB |
| $X_{TALK(ADJ)}$ | Crosstalk adjacent | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 20 | 25°C | 3.3 V | | –74 | | dB |
| THD | Total harmonic distortion | $R_L$ = 600 Ω, $C_L$ = 50 pF, | f = 20 Hz to 20 kHz, see Figure 22 | 25°C | 3.3 V | | 0.21% | | |
| **Supply** | | | | | | | | | |
| $I_+$ | Positive supply current | $V_I$ = $V_+$ or GND, | Switch ON or OFF | 25°C | 3.6 V | | 2.5 | 7 | μA |
| | | | | Full | | | | 10 | |

## 6.6 Electrical Characteristics for 2.5-V Supply

$V_+$ = 2.3 V to 2.7 V, $T_A$ = –40°C to 85°C (unless otherwise noted)[1]

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| **Analog Switch** | | | | | | | | | |
| $V_D$, $V_S$ | Analog signal range | | | | | 0 | | $V_+$ | V |
| $r_{on}$ | ON-state resistance | 0 ≤ $V_S$ ≤ $V_+$, $I_D$ = –24 mA, | Switch ON, see Figure 12 | 25°C | 2.3 V | | 20.5 | 22 | Ω |
| | | | | Full | | | | 24 | |
| $\Delta r_{on}$ | ON-state resistance match between channels | $V_S$ = 1.6 V, $I_D$ = –24 mA, | Switch ON, see Figure 12 | 25°C | 2.3 V | | 1 | 2 | Ω |
| | | | | Full | | | | 3 | |
| $r_{on(flat)}$ | ON-state resistance flatness | 0 ≤ $V_S$ ≤ $V_+$, $I_D$ = –24 mA, | Switch ON, see Figure 12 | 25°C | 2.3 V | | 16 | 18 | Ω |
| | | | | Full | | | | 20 | |
| $I_{S(OFF)}$ | S OFF leakage current | $V_S$ = 0.5 V, $V_D$ = 2.2 V, or $V_S$ = 2.2 V, $V_D$ = 0.5 V, | Switch OFF, see Figure 13 | 25°C | 2.7 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{SPWR(OFF)}$ | | $V_S$ = 0 to 2.7 V, $V_D$ = 2.7 V to 0, | | 25°C | 0 V | –1 | 0.5 | 1 | |
| | | | | Full | | –5 | | 5 | |
| $I_{D(OFF)}$ | D OFF leakage current | $V_S$ = 0.5 V, $V_D$ = 2.2 V, or $V_S$ = 2.2 V, $V_D$ = 0.5V, | Switch OFF, see Figure 13 | 25°C | 2.7 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{DPWR(OFF)}$ | | $V_D$ = 0 to 2.7 V, $V_S$ = 2.7 V to 0, | | 25°C | 0 V | –1 | 0.5 | 1 | |
| | | | | Full | | –5 | | 5 | |
| $I_{S(ON)}$ | S ON leakage current | $V_S$ = 0.5 V, $V_D$ = Open, or $V_S$ = 2.2 V, $V_D$ = Open, | Switch ON, see Figure 14 | 25°C | 2.7 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| $I_{D(ON)}$ | D ON leakage current | $V_D$ = 0.5 V, $V_S$ = Open, or $V_D$ = 2.2 V, $V_S$ = Open, | Switch ON, see Figure 14 | 25°C | 2.7 V | –0.1 | 0.05 | 0.1 | μA |
| | | | | Full | | –0.2 | | 0.2 | |
| **Digital Control Inputs (IN1, IN2, $\overline{EN}$)**[2] | | | | | | | | | |
| $V_{IH}$ | Input logic high | | | Full | | 1.7 | | $V_+$ | V |
| $V_{IL}$ | Input logic low | | | Full | | 0 | | 0.7 | V |
| $I_{IH}$, $I_{IL}$ | Input leakage current | $V_I$ = $V_+$ or 0 | | 25°C | 2.7 V | –1 | 0.05 | 1 | μA |
| | | | | Full | | –1 | | 1 | |
| $Q_C$ | Charge injection | $V_{GEN}$ = 0, $R_{GEN}$ = 0, $C_L$ = 0.1 nF, | See Figure 21 | 25°C | 2.5 V | | | | pC |
| $C_{S(OFF)}$ | S OFF capacitance | $V_S$ = $V_+$ or GND, Switch OFF, | See Figure 15 | 25°C | 2.5 V | | 4.5 | | pF |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $V_+$ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Product Folder Links: *TS3A5017*

## Electrical Characteristics for 2.5-V Supply (continued)

$V_+$ = 2.3 V to 2.7 V, $T_A$ = –40°C to 85°C (unless otherwise noted)[1]

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| $C_{D(OFF)}$ | D OFF capacitance | $V_D = V_+$ or GND, Switch OFF, | See Figure 15 | 25°C | 2.5 V | | 18.5 | | pF |
| $C_{S(ON)}$ | S ON capacitance | $V_S = V_+$ or GND, Switch ON, | See Figure 15 | 25°C | 2.5 V | | 24 | | pF |
| $C_{D(ON)}$ | D ON capacitance | $V_D = V_+$ or GND, Switch ON, | See Figure 15 | 25°C | 2.5 V | | 24 | | pF |
| $C_I$ | Digital input capacitance | $V_I = V_+$ or GND, | See Figure 15 | 25°C | 2.5 V | | 2 | | pF |
| BW | Bandwidth | $R_L$ = 50 Ω, Switch ON, | See Figure 17 | 25°C | 2.5 V | | 165 | | MHz |
| $O_{ISO}$ | OFF isolation | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 18 | 25°C | 2.5 V | | –69 | | dB |
| $X_{TALK}$ | Crosstalk | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 19 | 25°C | 2.5 V | | –69 | | dB |
| $X_{TALK(ADJ)}$ | Crosstalk adjacent | $R_L$ = 50 Ω, f = 1 MHz, | See Figure 20 | 25°C | 2.5 V | | –74 | | dB |
| THD | Total harmonic distortion | $R_L$ = 600 Ω, $C_L$ = 50 pF, | f = 20 Hz to 20 kHz, see Figure 22 | 25°C | 2.5 V | | 0.29% | | |
| **Supply** | | | | | | | | | |
| $I_+$ | Positive supply current | $V_I = V_+$ or GND, | Switch ON or OFF | 25°C | 2.7 V | | 2.5 | 7 | μA |
| | | | | Full | | | | 10 | |

## 6.7 Switching Characteristics for 3.3-V supply

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| $t_{ON}$ | Turnon time | $V_D$ = 2 V, $R_L$ = 300 Ω, | $C_L$ = 35 pF, see Figure 16 | 25°C | 3.3 V | 1 | 5 | 9.5 | ns |
| | | | | Full | 3 V to 3.6 V | 1 | | 10.5 | |
| $t_{OFF}$ | Turnoff time | $V_D$ =2 V, $R_L$ = 300 Ω, | $C_L$ = 35 pF, see Figure 16 | 25°C | 3.3 V | 0.5 | 1.5 | 3.5 | ns |
| | | | | Full | 3 V to 3.6 V | 0.5 | | 4.5 | |

## 6.8 Switching Characteristics for 2.5-V supply

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | $T_A$ | $V_+$ | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| $t_{ON}$ | Turnon time | $V_{COM}$ = 2 V, $R_L$ = 300 Ω, | $C_L$ = 35 pF, see Figure 16 | 25°C | 2.5 V | 1.5 | 5 | 8 | ns |
| | | | | Full | 2.3 V to 2.7 V | 1 | | 10 | |
| $t_{OFF}$ | Turnoff time | $V_{COM}$ =2 V, $R_L$ = 300 Ω, | $C_L$ = 35 pF, see Figure 16 | 25°C | 2.5 V | 0.3 | 2 | 4.5 | ns |
| | | | | Full | 2.3 V to 2.7 V | 0.3 | | 6 | |

Product Folder Links: *TS3A5017*

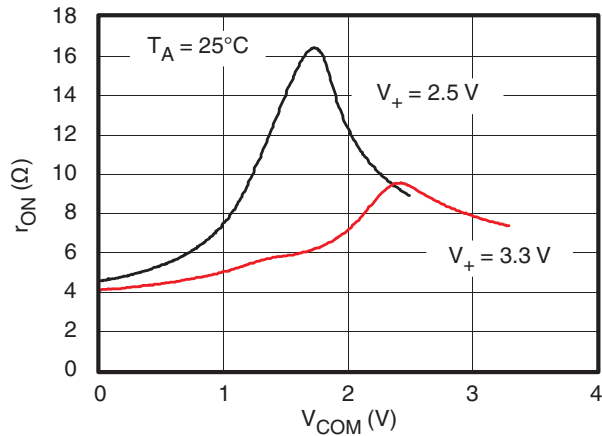## 6.9 Typical Characteristics



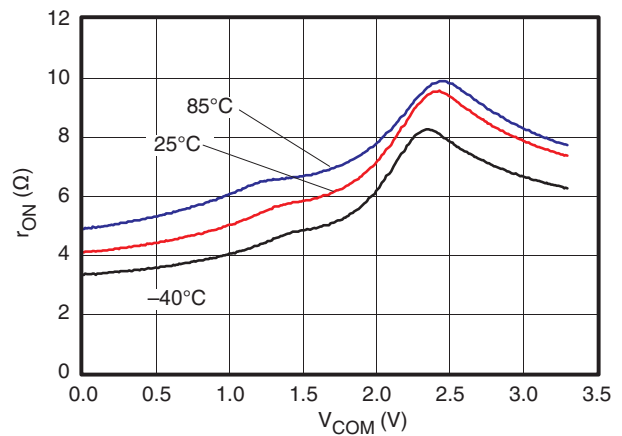Figure 1. r$_{on}$ vs V$_{COM}$



Figure 2. r$_{on}$ vs V$_{COM}$ (V$_+$ = 3.3 V)
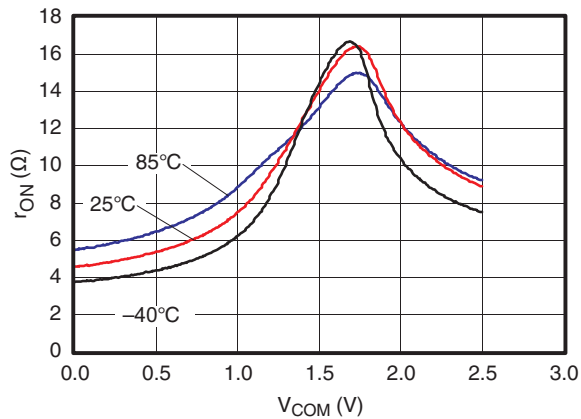


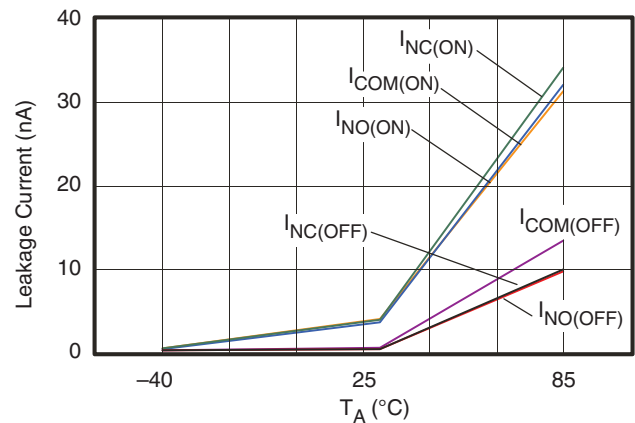Figure 3. r$_{on}$ vs V$_{COM}$ (V$_+$ = 2.5 V)



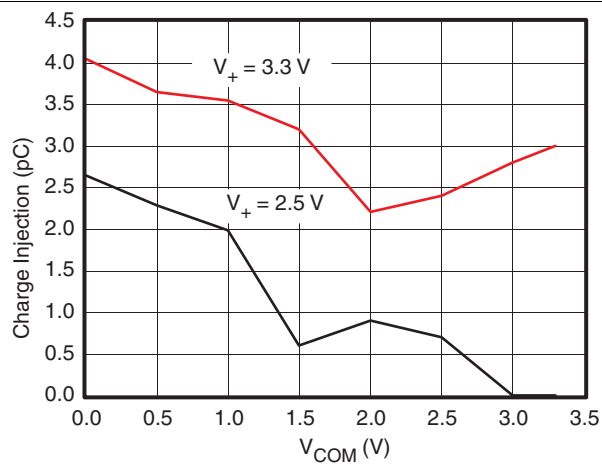Figure 4. Leakage Current vs Temperature (V$_+$ = 3.6 V)



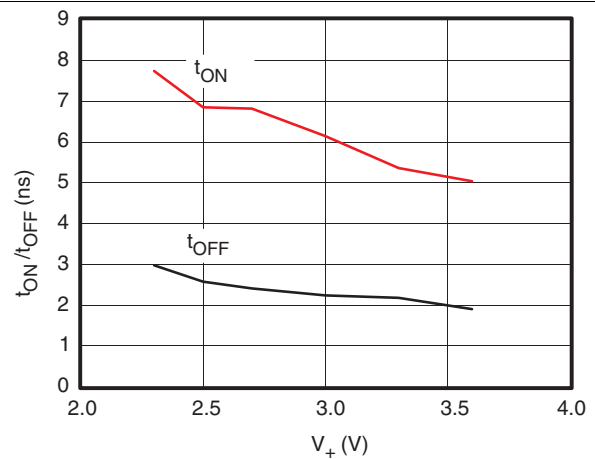Figure 5. Charge Injection (Q$_C$) vs V$_{COM}$



Figure 6. t$_{ON}$ and t$_{OFF}$ vs Supply Voltage

Product Folder Links: *TS3A5017*
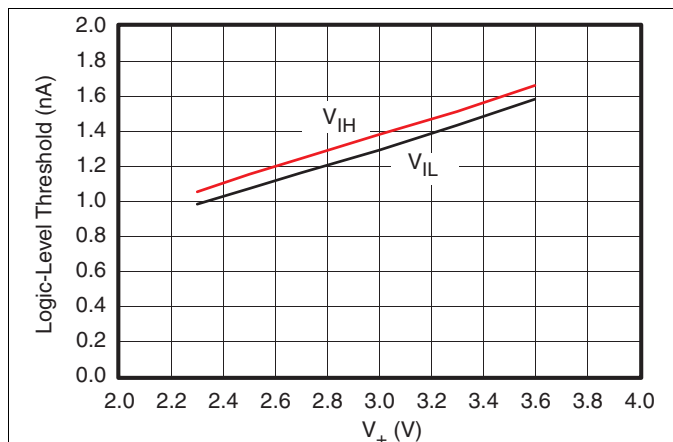
## Typical Characteristics (continued)
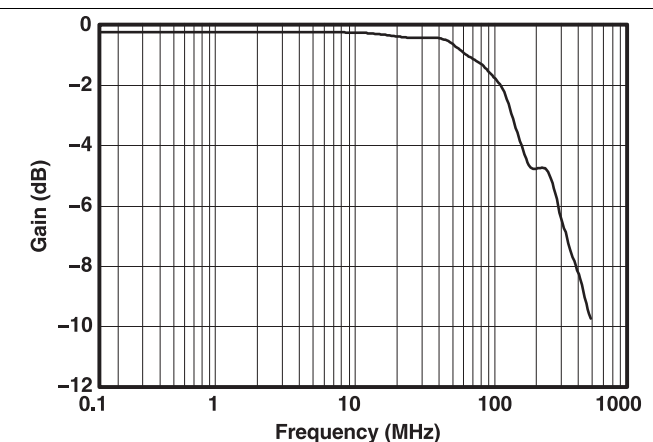


**Figure 7. Logic-Level Threshold vs V$_+$**



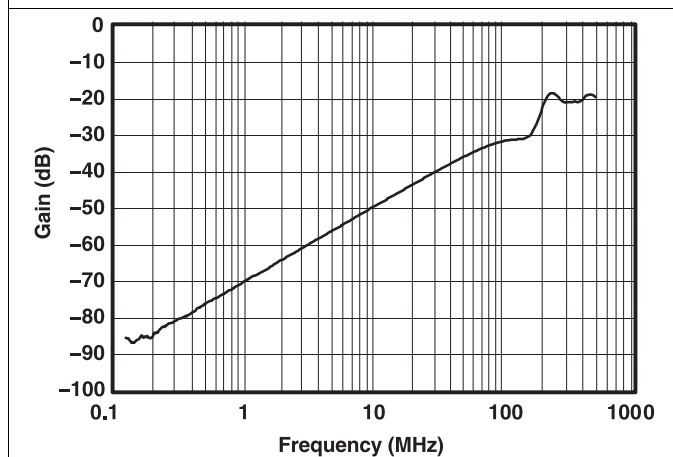**Figure 8. Bandwidth (Gain vs Frequency) (V$_+$ = 3.3 V)**



**Figure 9. OFF Isolation and Crosstalk vs Frequency (V$_+$ = 3.3 V)**
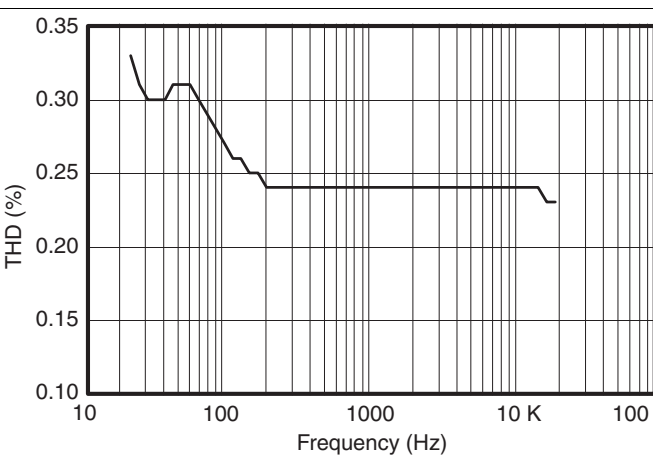


**Figure 10. Total Harmonic Distortion vs Frequency**
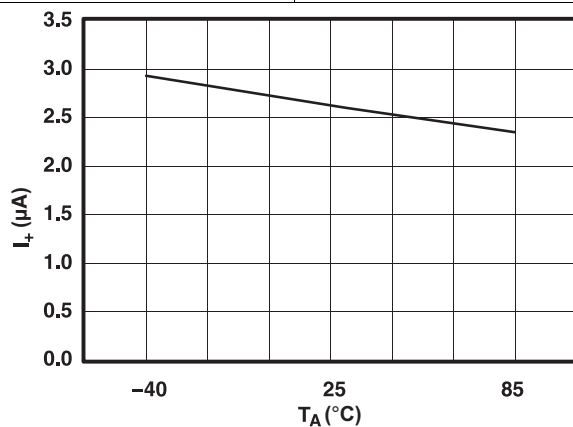


**Figure 11. Power-Supply Current vs Temperature (V$_+$ = 3.6 V)**

# 7 Parameter Measurement Information
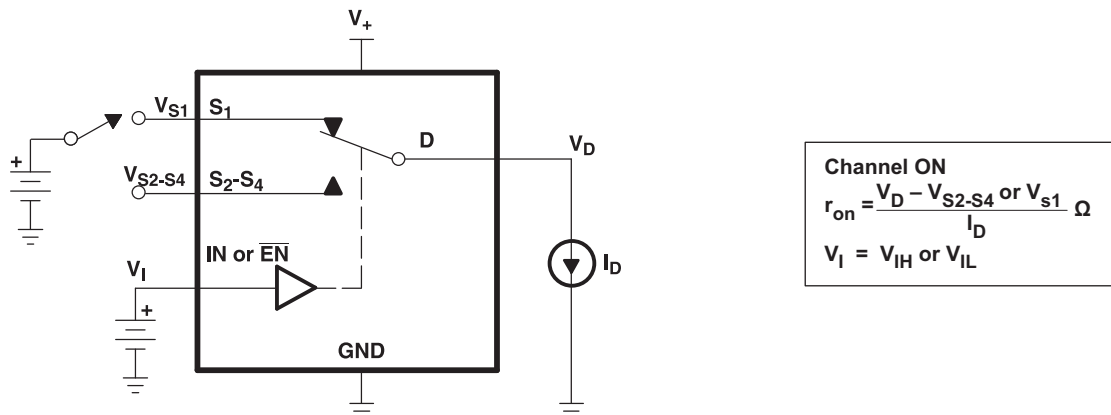


Figure 12. ON-State Resistance ($r_{on}$)

Channel ON

$$r_{on} = \frac{V_D - V_{S2\text{-}S4} \text{ or } V_{s1}}{I_D} \ \Omega$$

$V_I = V_{IH} \text{ or } V_{IL}$
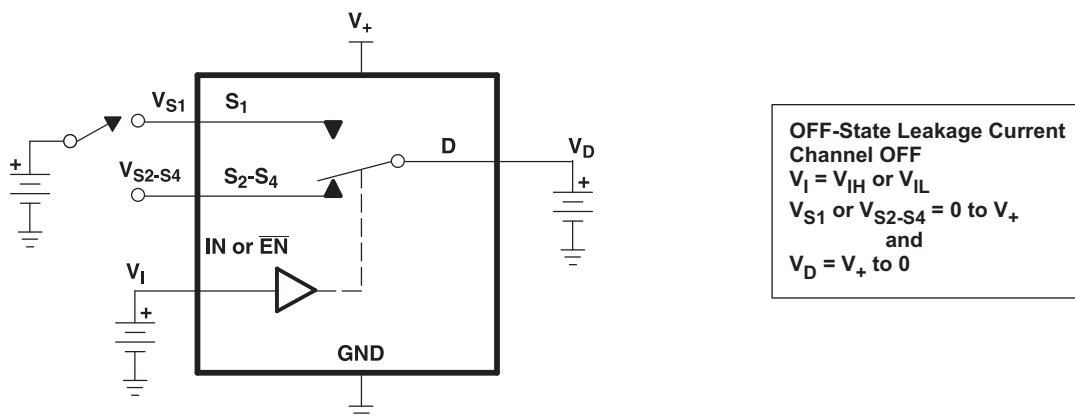


Figure 13. OFF-State Leakage Current ($I_{D(OFF)}$, $I_{S(OFF)}$)

OFF-State Leakage Current
Channel OFF
$V_I = V_{IH}$ or $V_{IL}$
$V_{S1}$ or $V_{S2\text{-}S4}$ = 0 to $V_+$
and
$V_D = V_+$ to 0
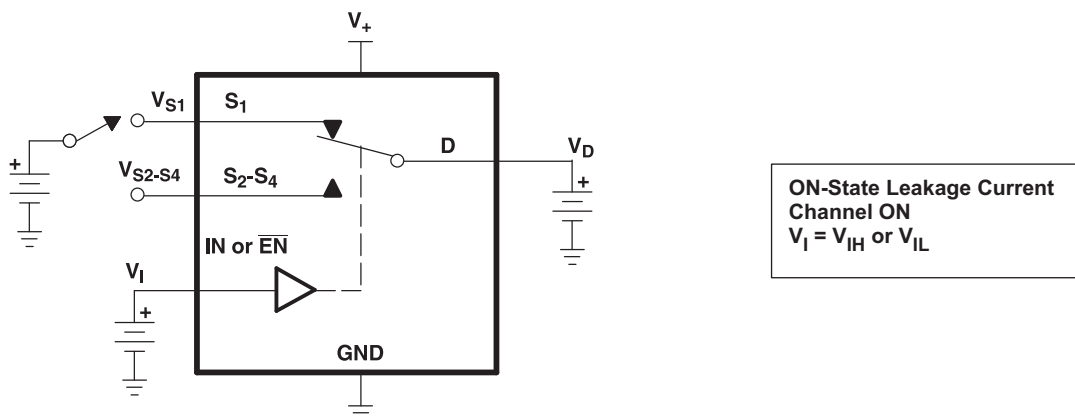


Figure 14. ON-State Leakage Current ($I_{D(ON)}$, $I_{S(ON)}$)

ON-State Leakage Current
Channel ON
$V_I = V_{IH}$ or $V_{IL}$

Product Folder Links: *TS3A5017*

## Parameter Measurement Information  (continued)



**VBIAS = V+ to GND**
**VI = VIH or VIL**

**Capacitance is measured at S1, S2-S4, D, and IN inputs during ON and OFF conditions.**
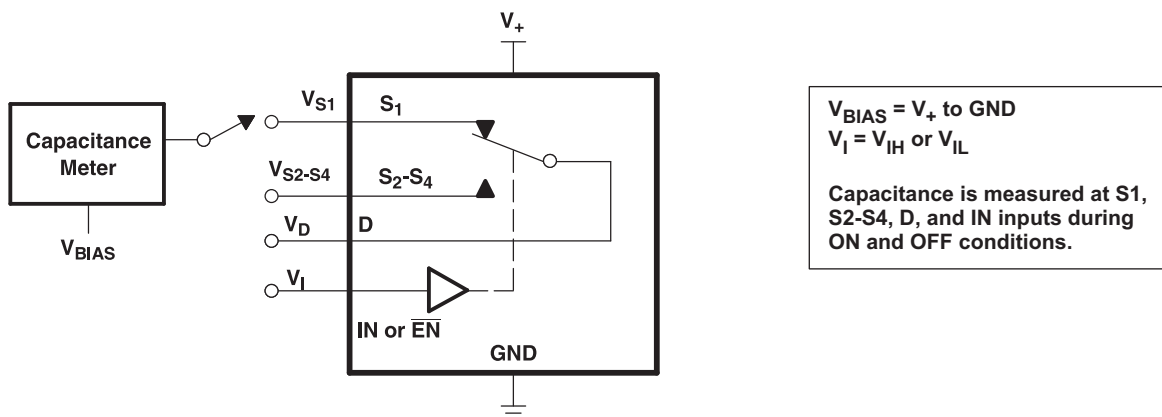
**Figure 15.  Capacitance ($C_I$, $C_{D(OFF)}$, $C_{D(ON)}$, $C_{S(OFF)}$, $C_{S(ON)}$)**
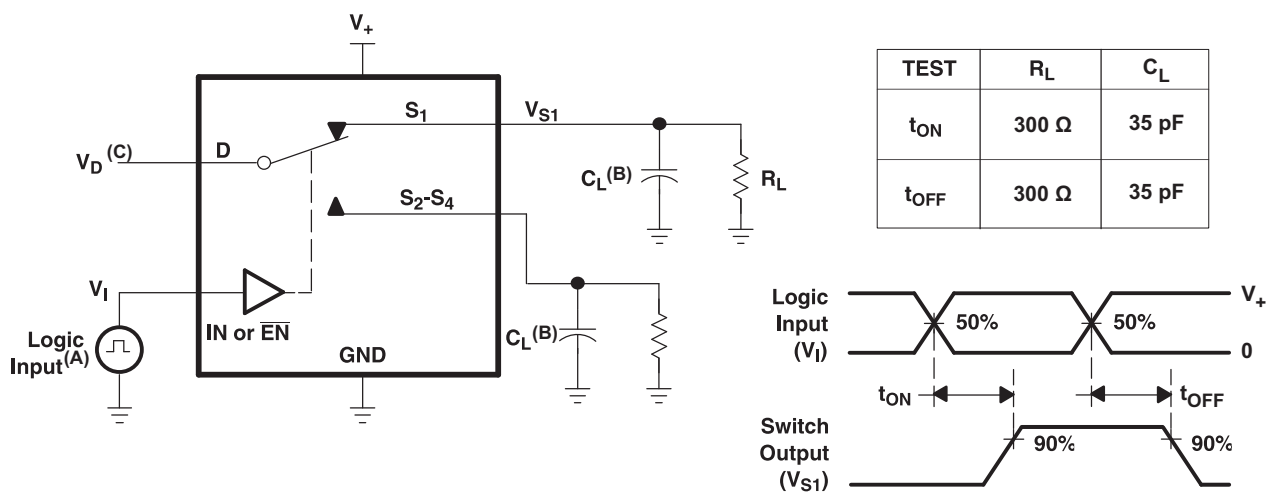


| TEST | $R_L$ | $C_L$ |
|---|---|---|
| $t_{ON}$ | 300 Ω | 35 pF |
| $t_{OFF}$ | 300 Ω | 35 pF |

A.   All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ < 5 ns, $t_f$ < 5 ns.
B.   $C_L$ includes probe and jig capacitance.
C.   See Electrical Characteristics for $V_D$.

**Figure 16.  Turnon ($t_{ON}$) and Turnoff Time ($t_{OFF}$)**



**Channel ON: S1 to D**
**VI = V+ or GND**

**Network Analyzer Setup**

**Source Power = 0 dBm (632-mV P-P at 50-Ω load)**

**DC Bias = 350 mV**

**Figure 17.  Bandwidth (BW)**

Product Folder Links: TS3A5017

## Parameter Measurement Information  (continued)



Channel OFF: S to D
$V_I = V_+$ or GND

**Network Analyzer Setup**

Source Power = 0 dBm
(632-mV P-P at 50-Ω load)

DC Bias = 350 mV
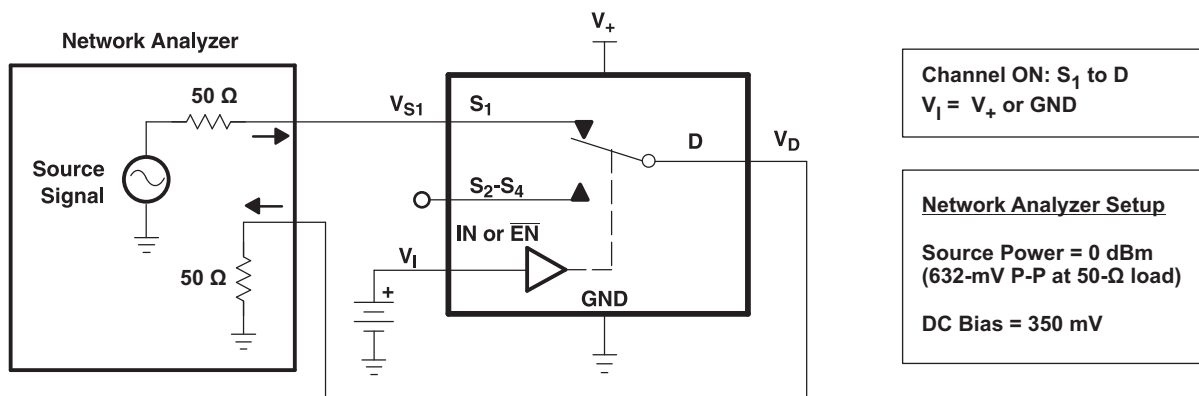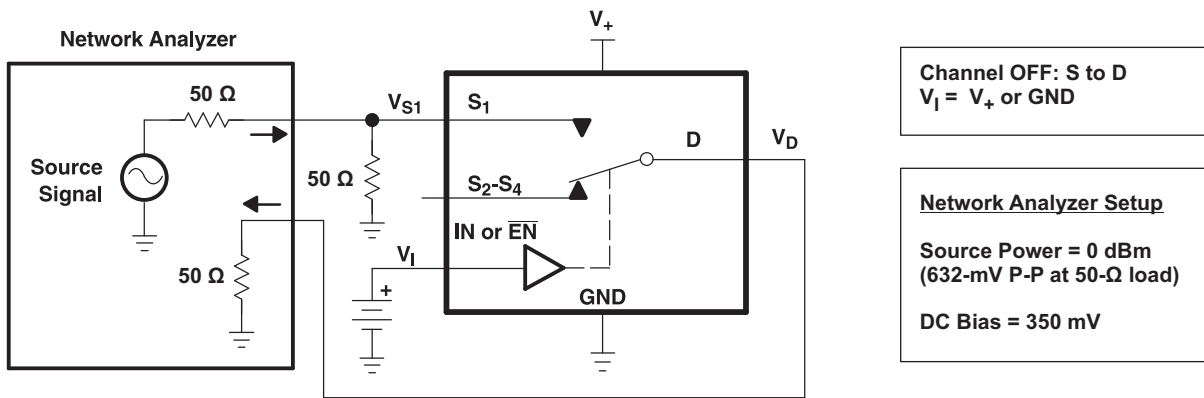
**Figure 18.  OFF Isolation ($O_{ISO}$)**



Channel ON: $S_1$ to D
Channel OFF: $S_2$-$S_4$ to D
$V_I = V_+$ or GND

**Network Analyzer Setup**

Source Power = 0 dBm
(632-mV P-P at 50-Ω load)

DC Bias = 350 mV
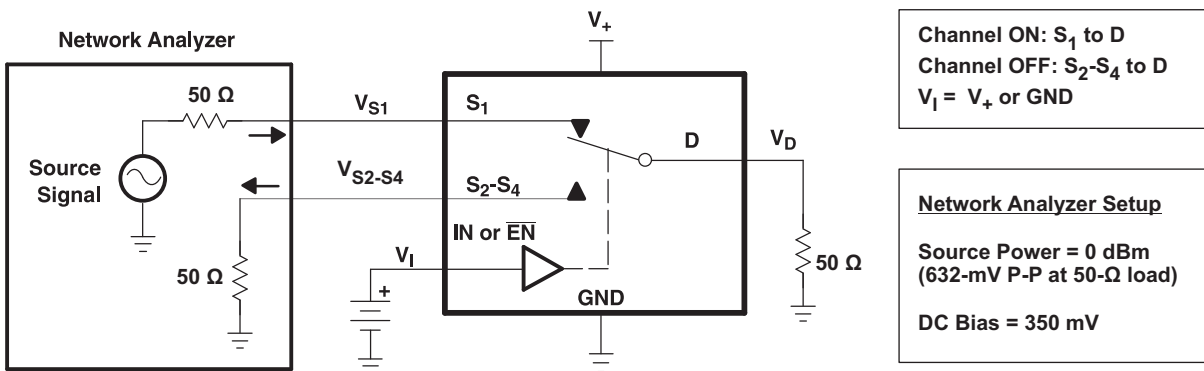
**Figure 19.  Crosstalk ($X_{TALK}$)**



Channel ON: $S_1$ to D

**Network Analyzer Setup**

Source Power = 0 dBm
(632-mV P-P at 50-Ω load)

DC Bias = 350 mV
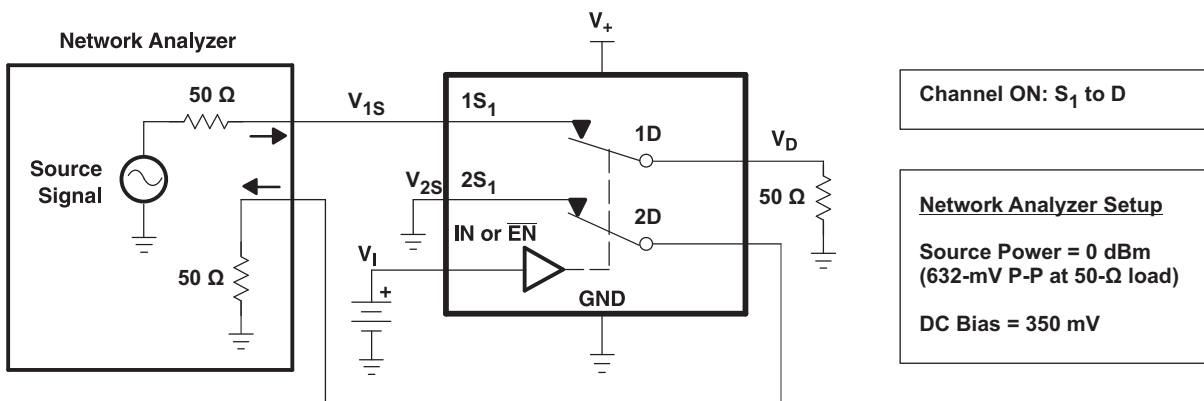
**Figure 20.  Adjacent Crosstalk ($X_{TALK}$)**

Product Folder Links: *TS3A5017*
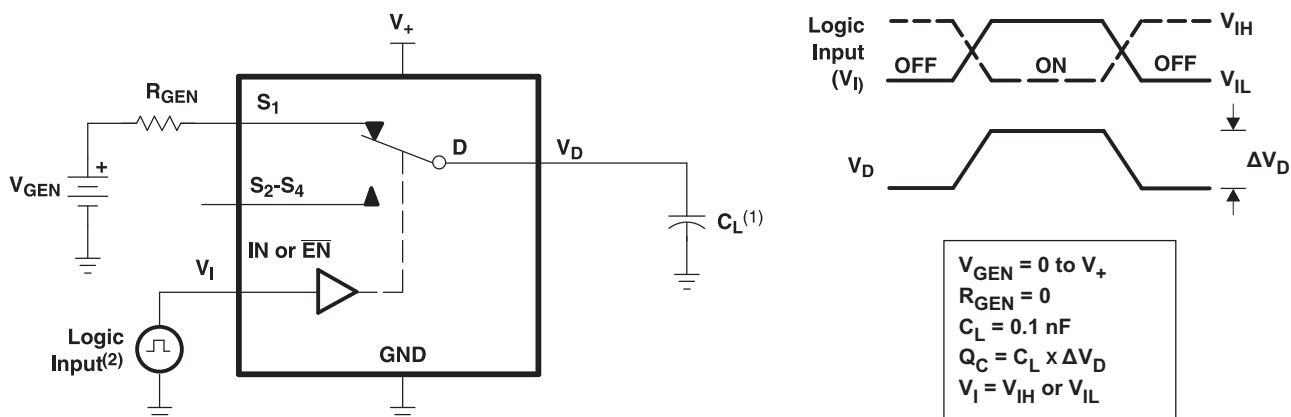
## Parameter Measurement Information  (continued)



A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ < 5 ns, $t_f$ < 5 ns.

B. $C_L$ includes probe and jig capacitance.

**Figure 21.  Charge Injection ($Q_C$)**
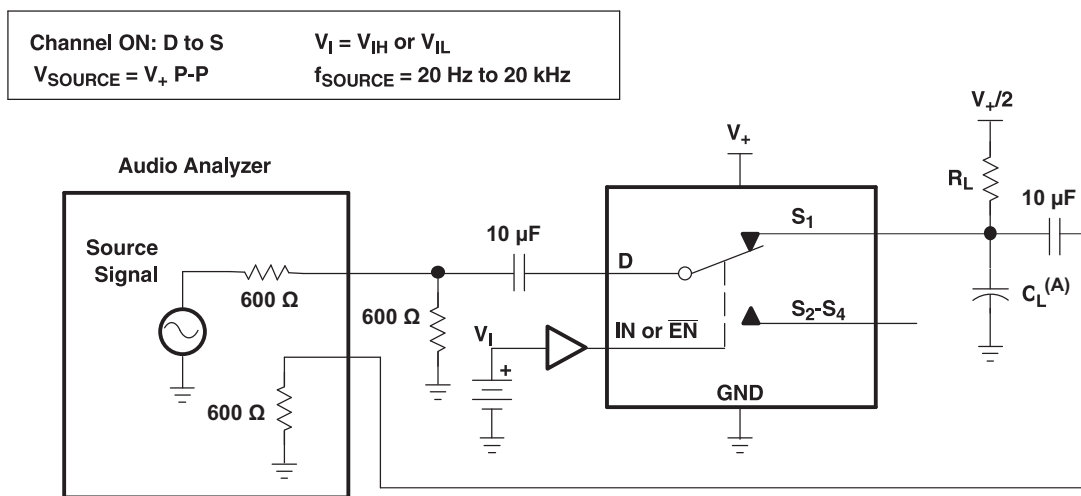


A. $C_L$ includes probe and jig capacitance.

**Figure 22.  Total Harmonic Distortion (THD)**

Product Folder Links: *TS3A5017*

# 8 Detailed Description

## 8.1 Overview

The TS3A5017 is a dual Single-Pole-4-Throw (SP4T) solid-state analog switch. The TS3A5017, like all analog switches, is bidirectional. Each D pin connects to its four respective S pins, with the switch connection dependent on the status of $\overline{EN}$, IN2, and IN1. See Table 1 for the switch configuration truth table.

## 8.2 Functional Block Diagram
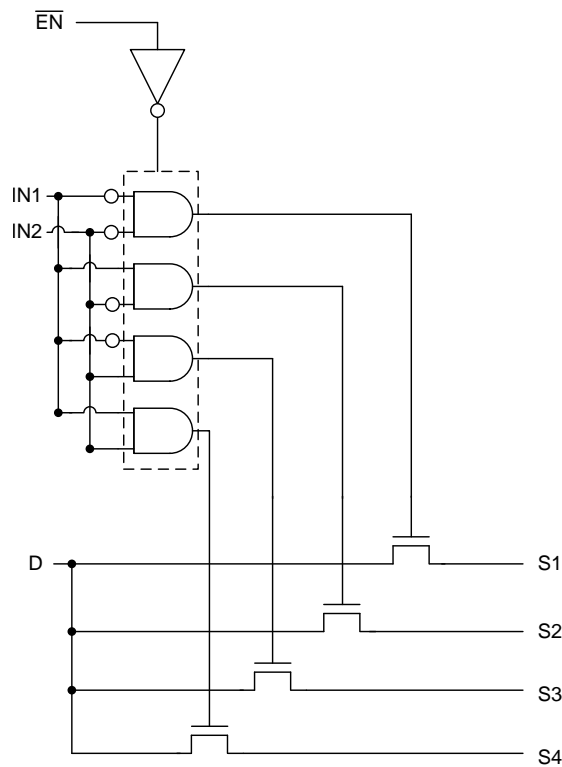


**Figure 23. Functional Block Diagram (Each Switch)**

## 8.3 Feature Description

Isolation in powered-down mode allows signals to be present at the inputs while the switch is powered off without causing damage to the device. The low ON-state resistance and low charge injection give the TS3A5017 better performance at higher speeds.

Product Folder Links: *TS3A5017*

## 8.4 Device Functional Modes

**Table 1. Function Table**

| $\overline{EN}$ | IN2 | IN1 | D TO S, S TO D |
|---|---|---|---|
| L | L | L | $D = S_1$ |
| L | L | H | $D = S_2$ |
| L | H | L | $D = S_3$ |
| L | H | H | $D = S_4$ |
| H | X | X | OFF |

Product Folder Links: *TS3A5017*

# 9 Application and Implementation

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**NOTE**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

---

## 9.1 Application Information

The TS3A5018 can be used in a variety of customer systems. The TS3A5018 can be used anywhere multiple analog or digital signals must be selected to pass across a single line.

## 9.2 Typical Application
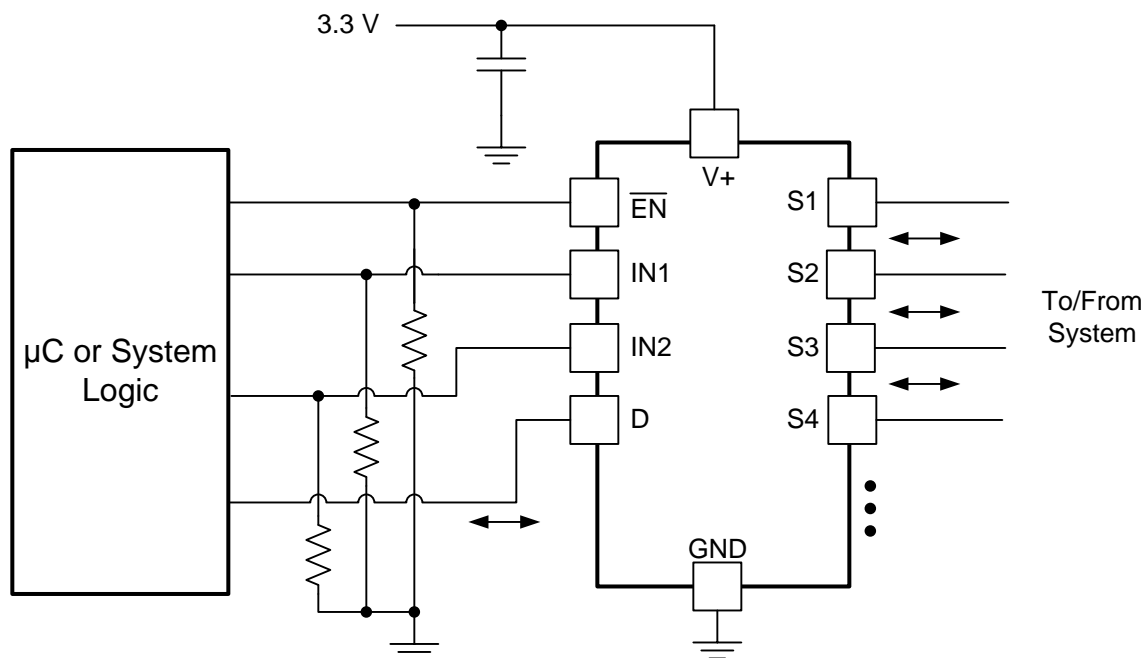


**Figure 24. System Schematic for TS3A5017**

### 9.2.1 Design Requirements

In this particular application, V+ was 3.3 V, although V+ is allowed to be any voltage specified in *Recommended Operating Conditions*. A decoupling capacitor is recommended on the V+ pin. See *Power Supply Recommendations* for more details.

### 9.2.2 Detailed Design Procedure

In this application, EN, IN1, and IN2 are, by default, pulled low to GND. Choose these resistor sizes based on the current driving strength of the GPIO, the desired power consumption, and the switching frequency (if applicable). If the GPIO is open-drain, use pullup resistors instead.

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Product Folder Links: *TS3A5017*

## Typical Application  (continued)

### 9.2.3  Application Curve
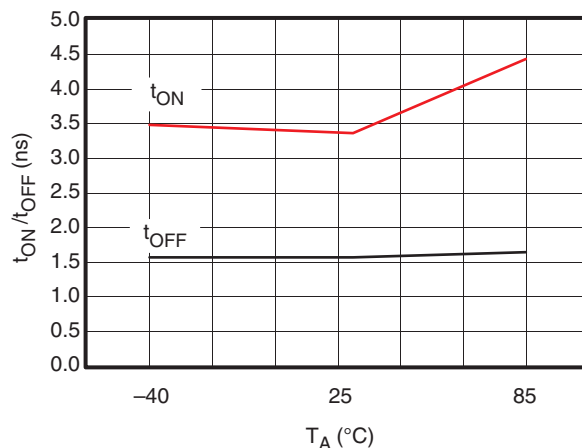


**Figure 25.  t$_{ON}$ and t$_{OFF}$ vs Temperature (V$_+$ = 3.3 V)**

## 10  Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*.

Each V$_{CC}$ terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-µF bypass capacitor is recommended. If there are multiple pins labeled V$_{CC}$, then a 0.01-µF or 0.022-µF capacitor is recommended for each V$_{CC}$ because the V$_{CC}$ pins will be tied together internally. For devices with dual-supply pins operating at different voltages, for example V$_{CC}$ and V$_{DD}$, a 0.1-µF bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 11  Layout

### 11.1  Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self–inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Below figure shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

Unused switch I/Os, such as NO, NC, and COM, can be left floating or tied to GND. However, the IN1, IN2, and EN pins must be driven high or low. Due to partial transistor turnon when control inputs are at threshold levels, floating control inputs can cause increased I$_{CC}$ or unknown switch selection states. See *Implications of Slow or Floating CMOS Inputs,* SCBA004 for more details.
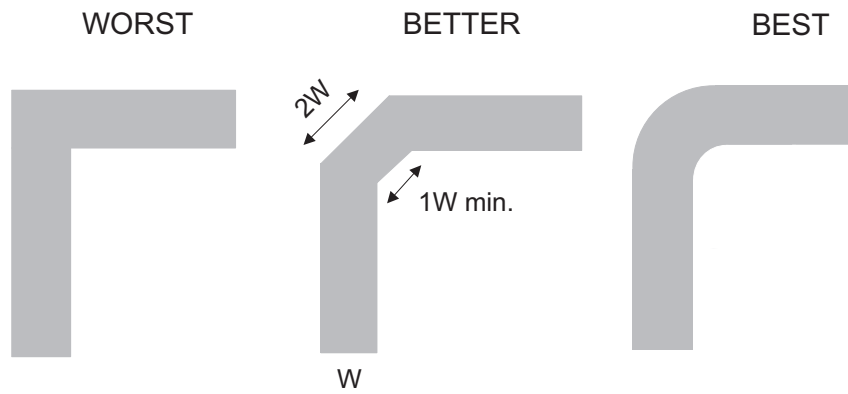
## 11.2 Layout Example

WORST          BETTER          BEST

2W

1W min.

W

**Figure 26. Trace Example**

Product Folder Links: *TS3A5017*

# 12 Device and Documentation Support

## 12.1 Device Support

### 12.1.1 Device Nomenclature

**Table 2. Parameter Description**

| SYMBOL | DESCRIPTION |
|---|---|
| $V_{COM}$ | Voltage at COM |
| $V_{NC}$ | Voltage at NC |
| $V_{NO}$ | Voltage at NO |
| $r_{on}$ | Resistance between COM and NC or NO ports when the channel is ON |
| $\Delta r_{on}$ | Difference of $r_{on}$ between channels in a specific device |
| $r_{on(flat)}$ | Difference between the maximum and minimum value of $r_{on}$ in a channel over the specified range of conditions |
| $I_{NC(OFF)}$ | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state |
| $I_{NC(ON)}$ | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open |
| $I_{NO(OFF)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state |
| $I_{NO(ON)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open |
| $I_{COM(OFF)}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the OFF state |
| $I_{COM(ON)}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the ON state and the output (NC or NO) open |
| $V_{IH}$ | Minimum input voltage for logic high for the control input (IN, $\overline{EN}$) |
| $V_{IL}$ | Maximum input voltage for logic low for the control input (IN, $\overline{EN}$) |
| $V_I$ | Voltage at the control input (IN, $\overline{EN}$) |
| $I_{IH}$, $I_{IL}$ | Leakage current measured at the control input (IN, $\overline{EN}$) |
| $t_{ON}$ | Turnon time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output NC or NO) signal when the switch is turning ON. |
| $t_{OFF}$ | Turnoff time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (NC or NO) signal when the switch is turning OFF. |
| $Q_C$ | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC or NO) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, $C_L$ is the load capacitance and $\Delta V_{COM}$ is the change in analog output voltage. |
| $C_{NC(OFF)}$ | Capacitance at the NC port when the corresponding channel (NC to COM) is OFF |
| $C_{NC(ON)}$ | Capacitance at the NC port when the corresponding channel (NC to COM) is ON |
| $C_{NO(OFF)}$ | Capacitance at the NC port when the corresponding channel (NO to COM) is OFF |
| $C_{NO(ON)}$ | Capacitance at the NC port when the corresponding channel (NO to COM) is ON |
| $C_{COM(OFF)}$ | Capacitance at the COM port when the corresponding channel (COM to NC) is OFF |
| $C_{COM(ON)}$ | Capacitance at the COM port when the corresponding channel (COM to NC) is ON |
| $C_I$ | Capacitance of control input (IN, $\overline{EN}$) |
| $O_{ISO}$ | OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM) in the OFF state. |
| $X_{TALK}$ | Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC1 to NO1). Adjacent crosstalk is a measure of unwanted signal coupling from an ON channel to an adjacent ON channel (NC1 to NC2) .This is measured in a specific frequency and in dB. |
| BW | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain. |
| THD | Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic. |
| $I_+$ | Static power-supply current with the control (IN) pin at $V_+$ or GND |

## 12.2 Documentation Support

### 12.2.1 Related Documentation

- *Implications of Slow or Floating CMOS Inputs,* SCBA004

## 12.3 Trademarks

All trademarks are the property of their respective owners.

## 12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.5 Glossary

SLYZ022 — *TI Glossary.*

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|---|---|---|---|---|---|---|---|---|---|---|---|
| TS3A5017D | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3A5017 | Samples |
| TS3A5017DBQR | ACTIVE | SSOP | DBQ | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | YA017 | Samples |
| TS3A5017DGVR | ACTIVE | TVSOP | DGV | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | YA017 | Samples |
| TS3A5017DR | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TS3A5017 | Samples |
| TS3A5017PW | ACTIVE | TSSOP | PW | 16 | 90 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | YA017 | Samples |
| TS3A5017PWG4 | ACTIVE | TSSOP | PW | 16 | 90 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | YA017 | Samples |
| TS3A5017PWR | ACTIVE | TSSOP | PW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | YA017 | Samples |
| TS3A5017PWRG4 | ACTIVE | TSSOP | PW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | YA017 | Samples |
| TS3A5017RGYR | ACTIVE | VQFN | RGY | 16 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | YA017 | Samples |
| TS3A5017RGYRG4 | ACTIVE | VQFN | RGY | 16 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | YA017 | Samples |
| TS3A5017RSVR | ACTIVE | UQFN | RSV | 16 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ZVL | Samples |

**(1)** The marketing status values are defined as follows:
**ACTIVE:** Product device recommended for new designs.
**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
**OBSOLETE:** TI has discontinued the production of the device.

**(2) RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

**(6)** Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TS3A5017 :**

• Automotive: TS3A5017-Q1

NOTE: Qualified Version Definitions:

      • Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# PACKAGE MATERIALS INFORMATION

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

**TAPE DIMENSIONS**

| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TS3A5017DBQR | SSOP | DBQ | 16 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TS3A5017DGVR | TVSOP | DGV | 16 | 2000 | 330.0 | 12.4 | 6.8 | 4.0 | 1.6 | 8.0 | 12.0 | Q1 |
| TS3A5017DR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| TS3A5017PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TS3A5017RGYR | VQFN | RGY | 16 | 3000 | 330.0 | 12.4 | 3.8 | 4.3 | 1.5 | 8.0 | 12.0 | Q1 |
| TS3A5017RSVR | UQFN | RSV | 16 | 3000 | 180.0 | 12.4 | 2.1 | 2.9 | 0.75 | 4.0 | 12.0 | Q1 |

# PACKAGE MATERIALS INFORMATION

**TEXAS INSTRUMENTS**

**TAPE AND REEL BOX DIMENSIONS**

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TS3A5017DBQR | SSOP | DBQ | 16 | 2500 | 340.5 | 338.1 | 20.6 |
| TS3A5017DGVR | TVSOP | DGV | 16 | 2000 | 367.0 | 367.0 | 35.0 |
| TS3A5017DR | SOIC | D | 16 | 2500 | 333.2 | 345.9 | 28.6 |
| TS3A5017PWR | TSSOP | PW | 16 | 2000 | 367.0 | 367.0 | 35.0 |
| TS3A5017RGYR | VQFN | RGY | 16 | 3000 | 367.0 | 367.0 | 35.0 |
| TS3A5017RSVR | UQFN | RSV | 16 | 3000 | 203.0 | 203.0 | 35.0 |

RGY (R−PVQFN−N16)                    PLASTIC QUAD FLATPACK NO−LEAD

$\frac{4,15}{3,85}$  A

B

15    10

16    9

$\frac{3,65}{3,35}$

1    8

Pin 1 Index Area
Top and Bottom

2    7

F

$\frac{1,00}{0,80}$

0,20 Nominal
Lead Frame

Seating Plane

0,08 C

$\frac{0,05}{0,00}$
Seating Height

C

2,50

0,50

16X $\frac{0,50}{0,30}$

2    7

1    THERMAL PAD    8

SIZE AND SHAPE
SHOWN ON SEPRATE SHEET

1,50

16    9

16X $\frac{0,30}{0,18}$

15    10

⊕ | 0,10 Ⓜ | C | A | B
0,05 Ⓜ | C

Bottom View

4203539−3/I  06/2011
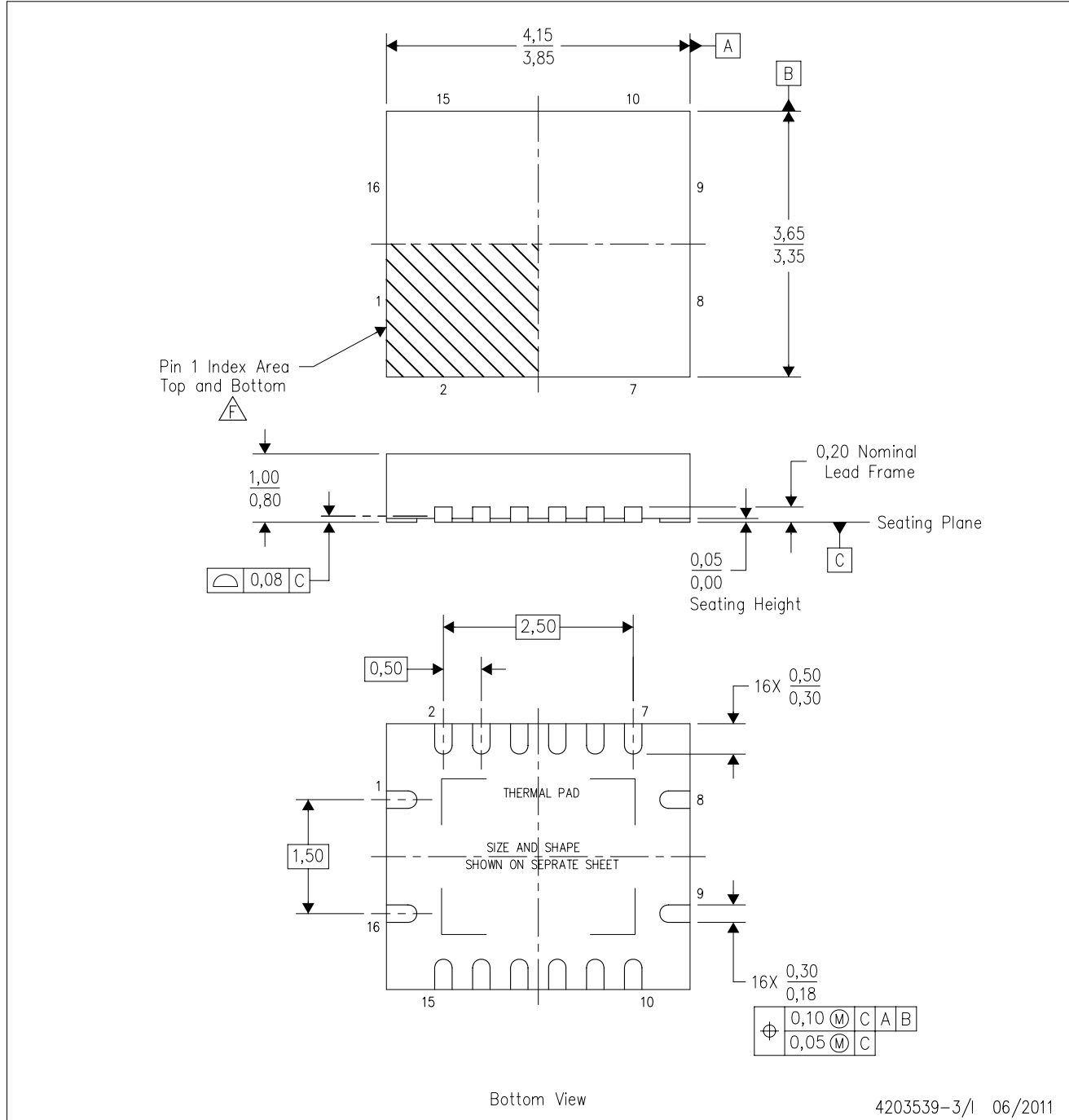
NOTES:  A.  All linear dimensions are in millimeters.  Dimensioning and tolerancing per ASME Y14.5M−1994.
        B.  This drawing is subject to change without notice.
        C.  QFN (Quad Flatpack No−Lead) package configuration.
        D.  The package thermal pad must be soldered to the board for thermal and mechanical performance.
        E.  See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
    F.  Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
        The Pin 1 identifiers are either a molded, marked, or metal feature.
        G.  Package complies to JEDEC MO−241 variation BA.

**TEXAS INSTRUMENTS**
www.ti.com

RGY (R−PVQFN−N16)                    PLASTIC QUAD FLATPACK NO−LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No−Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.
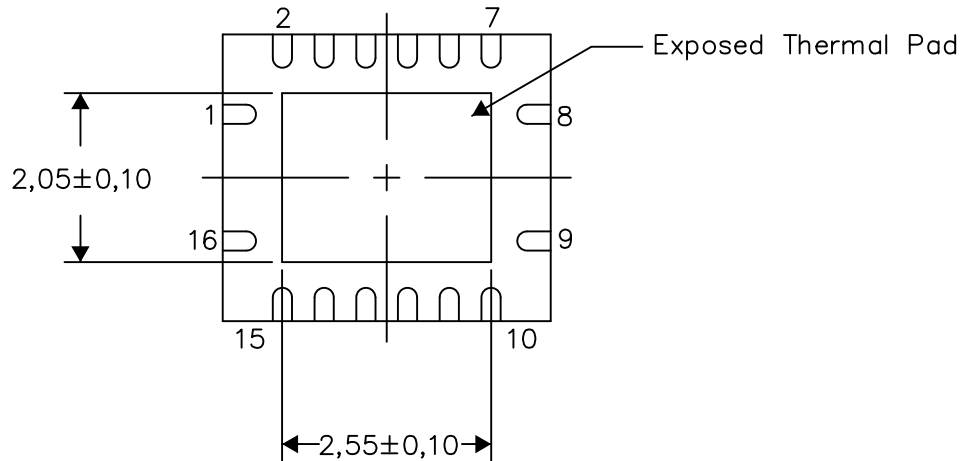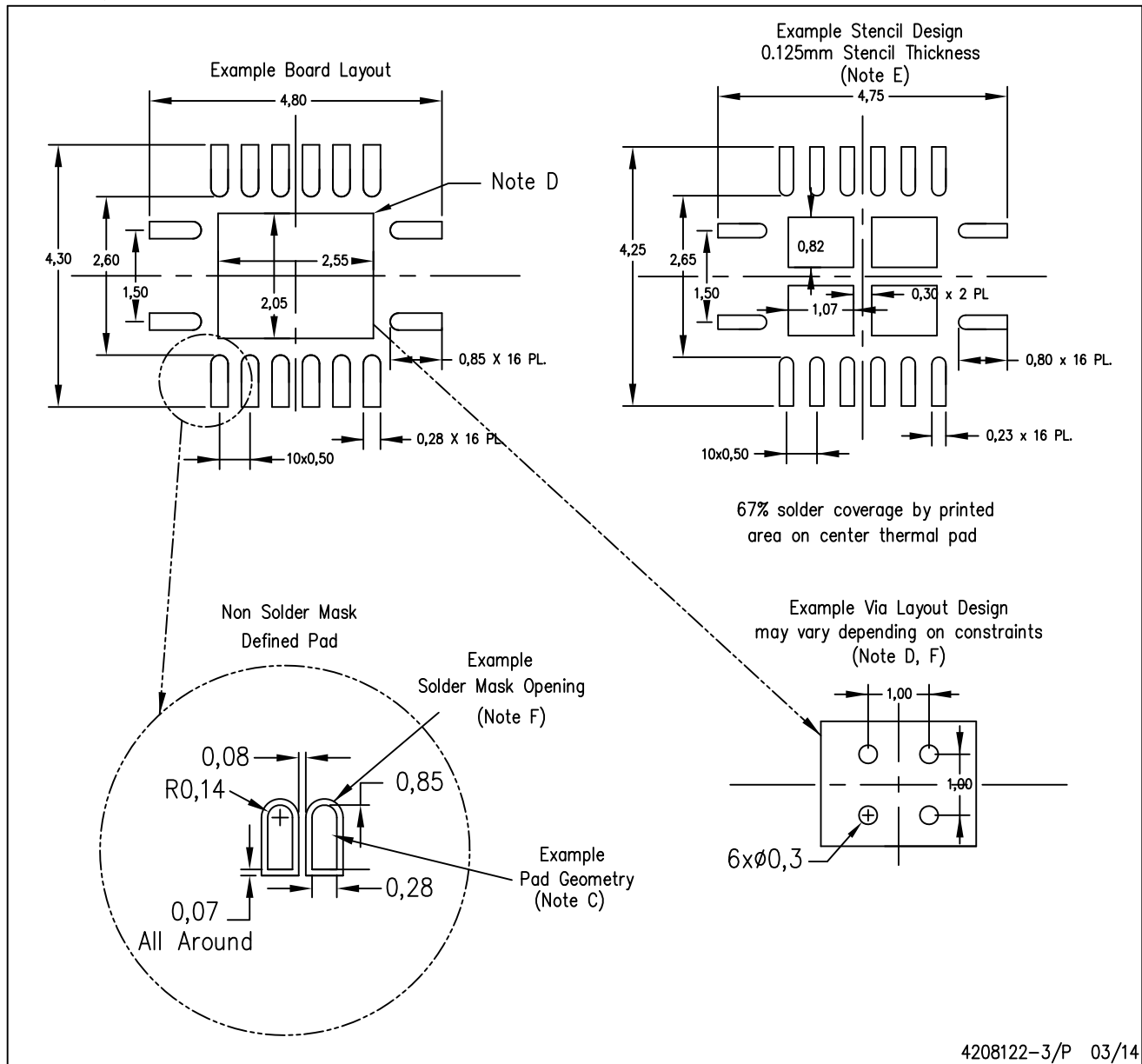


Bottom View

Exposed Thermal Pad Dimensions

4206353−3/P   03/14

NOTE:   All linear dimensions are in millimeters

RGY (R−PVQFN−N16)          PLASTIC QUAD FLATPACK NO−LEAD

Example Board Layout

Note D

4,80
4,30    2,60
2,55
1,50
2,05
0,85 X 16 PL.
0,28 X 16 PL.
10x0,50

Example Stencil Design
0.125mm Stencil Thickness
(Note E)

4,75
4,25    2,65
0,82
1,50    0,30 x 2 PL
1,07
0,80 x 16 PL.
0,23 x 16 PL.
10x0,50

67% solder coverage by printed
area on center thermal pad

Non Solder Mask
Defined Pad

Example
Solder Mask Opening
(Note F)

0,08
R0,14    0,85
0,07    0,28
All Around

Example
Pad Geometry
(Note C)

Example Via Layout Design
may vary depending on constraints
(Note D, F)

1,00
1,00
6x⌀0,3

4208122−3/P   03/14

NOTES:   A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Publication IPC−7351 is recommended for alternate designs.
         D.   This package is designed to be soldered to a thermal pad on the board.  Refer to Application Note, Quad Flat−Pack
              QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets
              for specific thermal information, via requirements, and recommended board layout.
              These documents are available at www.ti.com <http://www.ti.com>.
         E.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.  Customers should
              contact their board assembly site for stencil design recommendations.  Refer to IPC 7525 for stencil design considerations.
         F.   Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
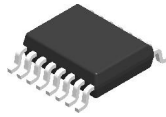
**TEXAS INSTRUMENTS**
www.ti.com
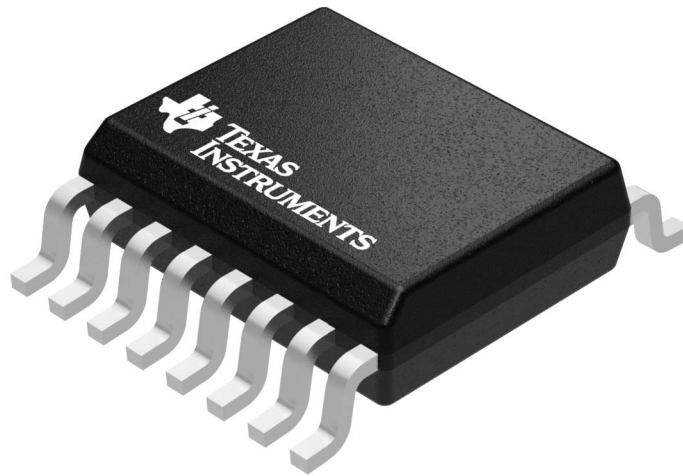
Images above are just a representation of the package family, actual package may vary.
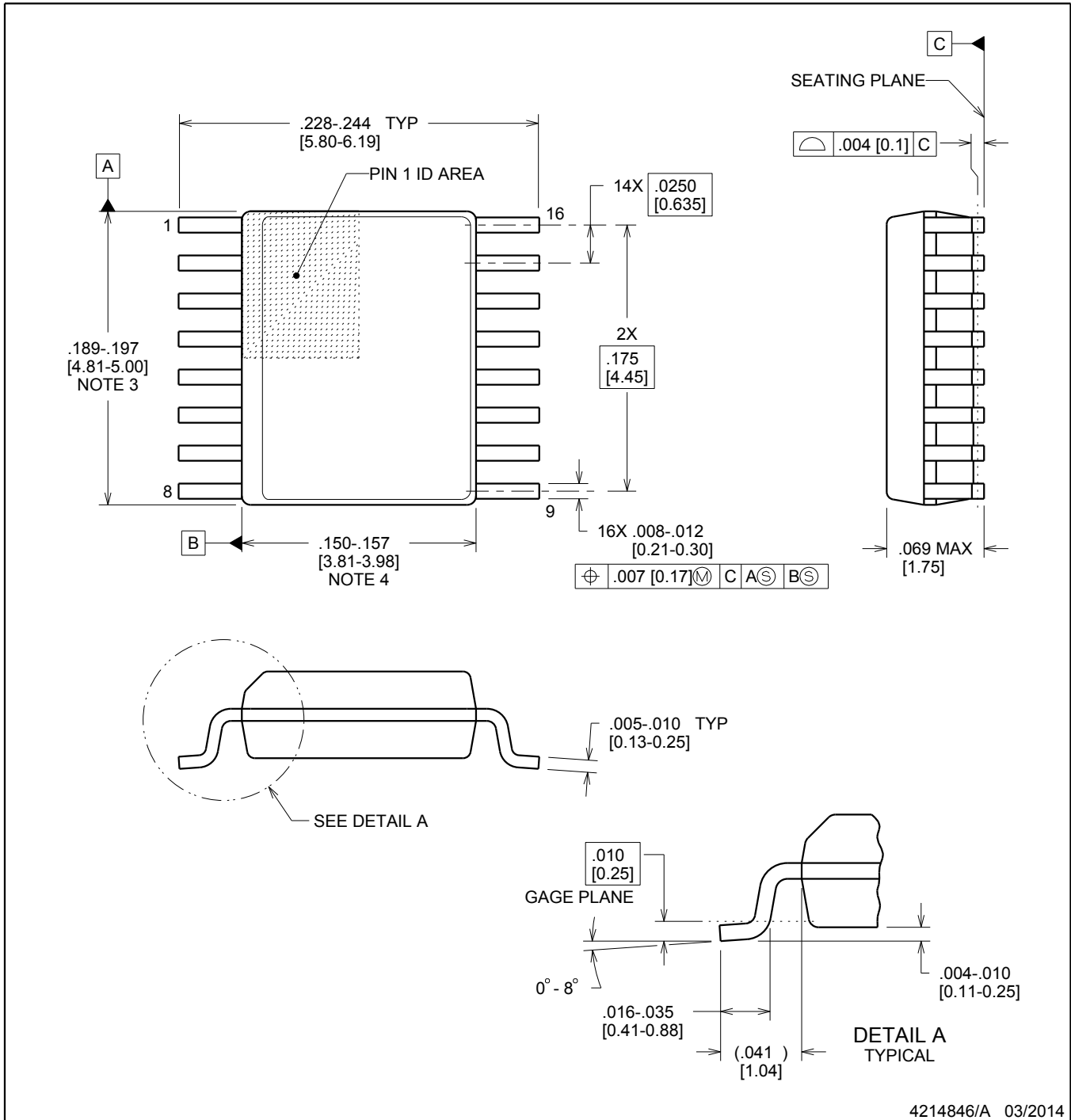Refer to the product data sheet for package details.

4073301-2/I

.228-.244   TYP
[5.80-6.19]

A

PIN 1 ID AREA

1

.189-.197
[4.81-5.00]
NOTE 3

8

B

.150-.157
[3.81-3.98]
NOTE 4

16

14X .0250
[0.635]

2X
.175
[4.45]

9

16X .008-.012
[0.21-0.30]

⊕ .007 [0.17] Ⓜ C AⓈ BⓈ

C

SEATING PLANE

⌒ .004 [0.1] C

.069 MAX
[1.75]

SEE DETAIL A

.005-.010   TYP
[0.13-0.25]

.010
[0.25]
GAGE PLANE

0° - 8°

.016-.035
[0.41-0.88]

(.041   )
[1.04]

.004-.010
[0.11-0.25]

**DETAIL A**
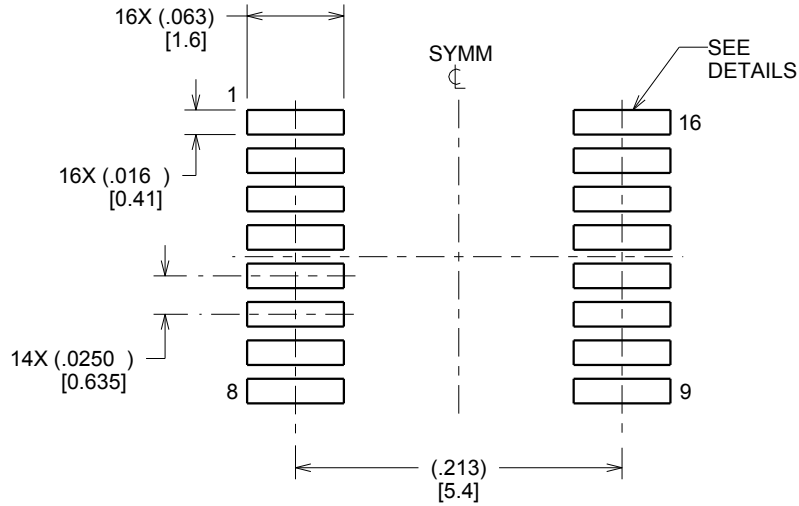TYPICAL

4214846/A   03/2014

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 inch, per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MO-137, variation AB.

16X (.063)
[1.6]

SYMM

SEE
DETAILS

1

16

16X (.016 )
[0.41]

14X (.0250 )
[0.635]

8

9

(.213)
[5.4]

LAND PATTERN EXAMPLE
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL

.002 MAX
[0.05]
ALL AROUND

.002 MIN
[0.05]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
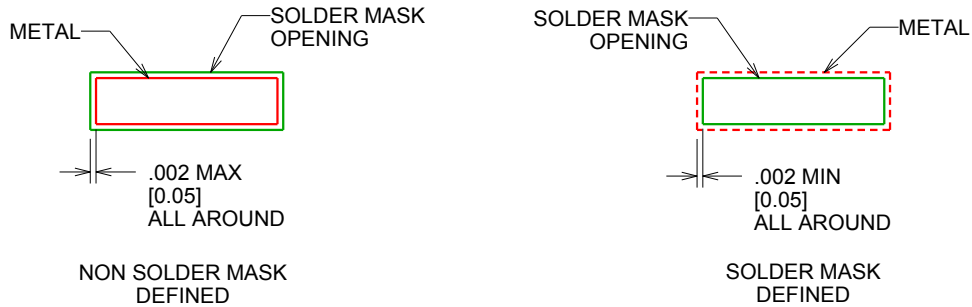
SOLDER MASK DETAILS

4214846/A   03/2014

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

16X (.063)
[1.6]

SYMM

1

16X (.016 )
[0.41]

16

SYMM

14X (.0250 )
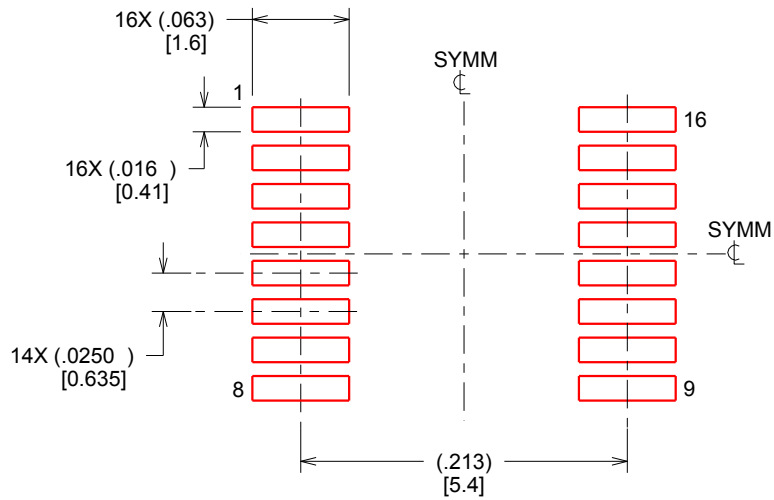[0.635]

8

9

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.127 MM] THICK STENCIL
SCALE:8X

4214846/A   03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R−PDSO−G16)                                                PLASTIC SMALL OUTLINE

0.394 (10,00)
0.386 (9,80)
/C\

16                                                    9

0.244 (6,20)
0.228 (5,80)

0.157 (4,00)
0.150 (3,80) /D\

1                                                    8

Pin 1
Index Area

0.050 (1,27)

0.020 (0,51)
0.012 (0,31)

⊕ 0.010 (0,25) Ⓜ

0.069 (1,75) Max

0.010 (0,25)
0.004 (0,10)

0.010 (0,25)
0.005 (0,13)

0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)          0°−8°

0.050 (1,27)
0.016 (0,40)

4040047−6/M   06/11

NOTES:   A.  All linear dimensions are in inches (millimeters).
         B.  This drawing is subject to change without notice.
      /C\  Body length does not include mold flash, protrusions, or gate burrs.  Mold flash, protrusions, or gate burrs shall
           not exceed 0.006 (0,15) each side.
      /D\  Body width does not include interlead flash.  Interlead flash shall not exceed 0.017 (0,43) each side.
         E.  Reference JEDEC MS−012 variation AC.

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www.ti.com

D (R−PDSO−G16)                                    PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

←14x1,27

16x0,55

16x1,50

←14x1,27

5,40

5.40

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

0,60

1,55

Example
Solder Mask Opening
(See Note E)

0,07

All Around

4211283−4/E  08/12

NOTES:    A.  All linear dimensions are in millimeters.
          B.  This drawing is subject to change without notice.
          C.  Publication IPC−7351 is recommended for alternate designs.
          D.  Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.  Customers should
              contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
          E.  Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

A

6.6
6.2 TYP

PIN 1 INDEX AREA

14X 0.65

16

SEATING
PLANE

C

△ 0.1 C

1

5.1
4.9
NOTE 3

2X

4.55

8

9

B

4.5
4.3
NOTE 4

16X 0.30
0.19

⊕ 0.1 Ⓜ C A B

1.2 MAX

SEE DETAIL A

(0.15) TYP

GAGE PLANE

0.25

0.15
0.05

0°-8°

0.75
0.50

DETAIL A
TYPICAL

4220204/A   02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

16X (1.5)

SYMM

1

16X (0.45)

(R0.05) TYP

16

SYMM

14X (0.65)

8

9

(5.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220204/A   02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

16X (1.5)

SYMM

1

16X (0.45)

(R0.05) TYP

16

SYMM

14X (0.65)

8

9

(5.8)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A   02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
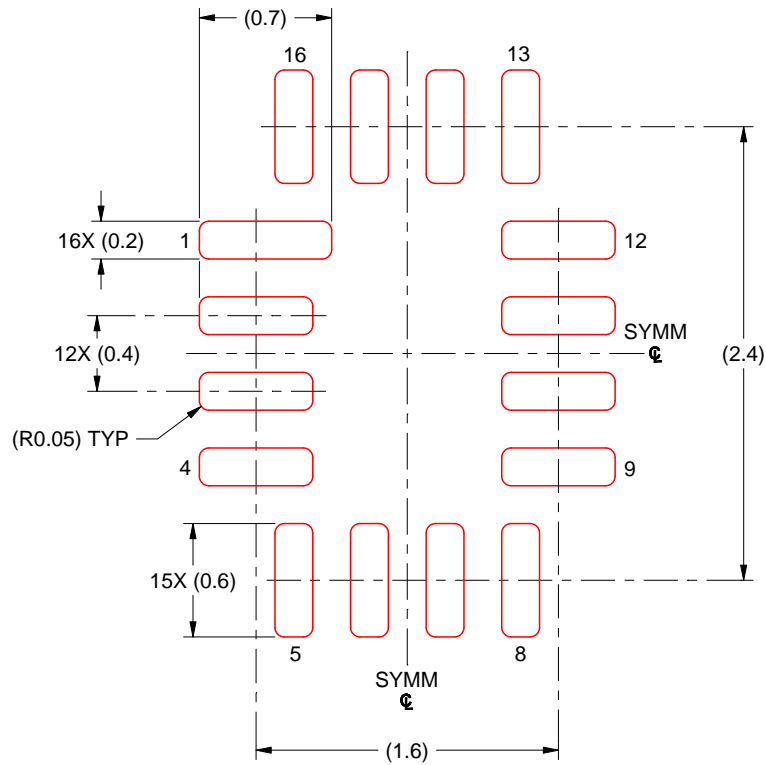9. Board assembly site may have different recommendations for stencil design.

B | 1.85 1.75 | A

PIN 1 INDEX AREA

2.65
2.55

0.55
0.45

0.05
0.00

C

SEATING PLANE

0.05 C

2X 1.2

SYMM

5          8

15X 0.45
0.35

4                    9

2X 1.2

SYMM

12X 0.4

1

16                   13

12

16X 0.25
0.15

0.07 (M) C A B
0.05 (M)

0.55
0.45

PIN 1 ID
(45° X 0.1)

(0.13) TYP
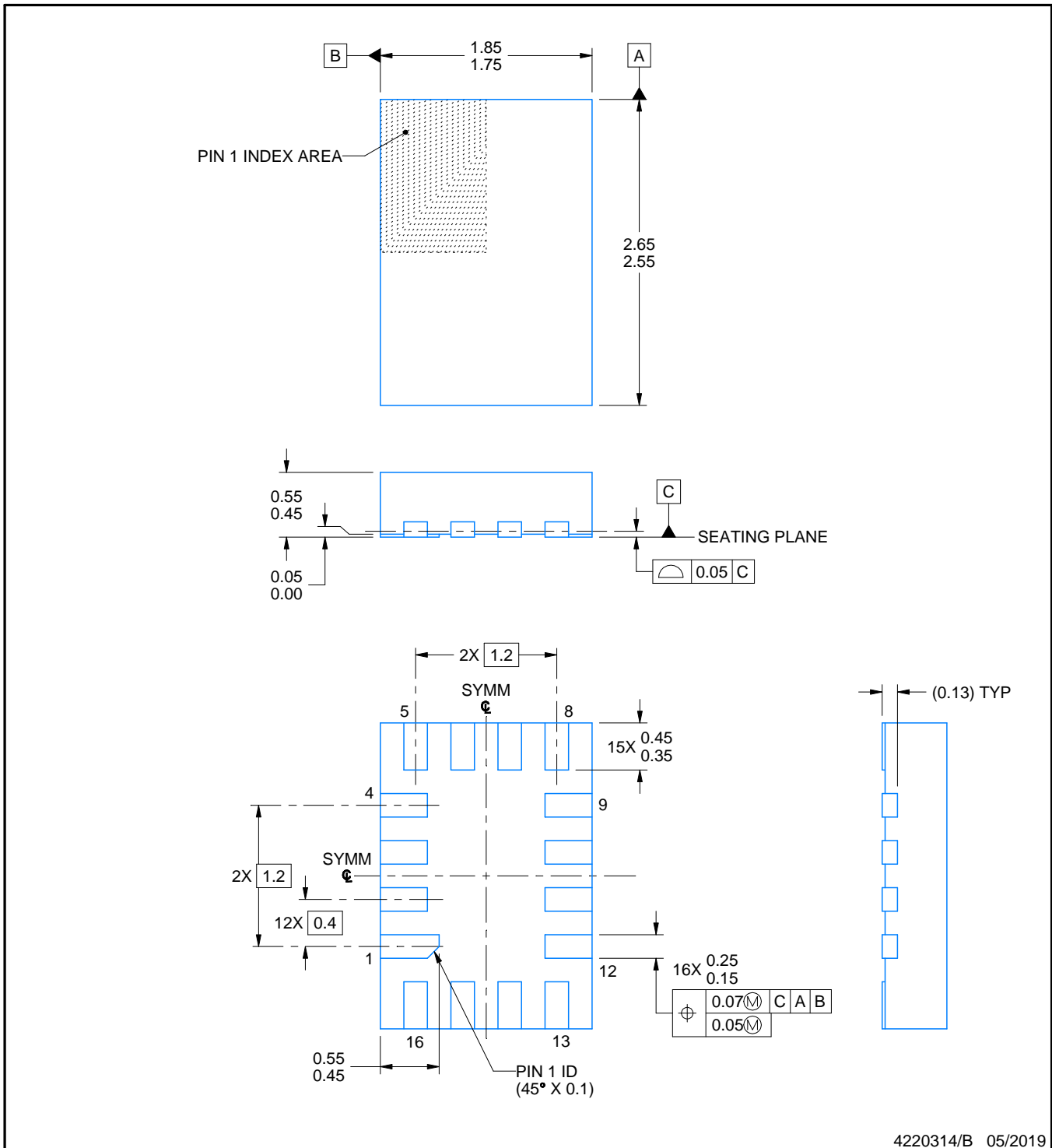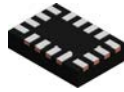
4220314/B   05/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.

SYMM

(0.7)

16

13

SEE SOLDER MASK
DETAIL

16X (0.2)

1

12

12X (0.4)

SYMM

(2.4)

(R0.05) TYP

4

9

15X (0.6)

5

8

(1.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X

0.05 MAX
ALL AROUND

METAL EDGE

EXPOSED METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED
(PREFERRED)

0.05 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

EXPOSED
METAL

SOLDER MASK
OPENING

SOLDER MASK DEFINED

SOLDER MASK DETAILS

4220314/B   05/2019

NOTES: (continued)

3. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

(0.7)

16  13

16X (0.2)  1  12

12X (0.4)

(R0.05) TYP

SYMM ℄

(2.4)

4  9

15X (0.6)

5  8

SYMM ℄

(1.6)

SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 25X

4220314/B   05/2019

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.

**DGV (R-PDSO-G**)**                                    **PLASTIC SMALL-OUTLINE**

**24 PINS SHOWN**

| DIM \ PINS ** | 14 | 16 | 20 | 24 | 38 | 48 | 56 |
|---|---|---|---|---|---|---|---|
| A MAX | 3,70 | 3,70 | 5,10 | 5,10 | 7,90 | 9,80 | 11,40 |
| A MIN | 3,50 | 3,50 | 4,90 | 4,90 | 7,70 | 9,60 | 11,20 |

4073251/E 08/00

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

**TEXAS INSTRUMENTS**
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